SN54HCT573 . . . J OR W PACKAGE SN74HCT573 . . . DB, DW, N, NS, OR PW PACKAGE

(TOP VIEW)

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- Operating Voltage Range of 4.5 V to 5.5 V
- High-Current 3-State Outputs Drive Bus Lines Directly or Up To 15 LSTTL Loads
- Low Power Consumption, 80-µA Max I<sub>CC</sub>
- Typical t<sub>pd</sub> = 21 ns
- ±6-mA Output Drive at 5 V
- Low Input Current of 1 μA Max
- Inputs Are TTL-Voltage Compatible
- Bus-Structured Pinout

#### description/ordering information

These octal transparent D-type latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. The 'HCT573 devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

While the latch-enable (LE) input is high, the Q outputs respond to the data (D) inputs. When LE is low, the outputs are latched to retain the data that was set up at the D inputs.

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance

	•	,	
OE		U <sub>20</sub>	] v <sub>cc</sub>
1D	2	19	] 1Q
2D	<b>[</b> ] 3	18	] 2Q
3D	4	17	] 3Q
4D	5	16	] 4Q
5D	6	15	] 5Q
6D	<b>[</b> 7	14	] 6Q
7D	8	13	] 7Q
8D	9	12	] 8Q
GND	[ 10	11	LE

SN54HCT573 . . . FK PACKAGE (TOP VIEW)

	2D 2D 2D 2C 2D	
<b>0 D</b>		~~
3D	<b>∐</b> 4 18 <b>∐</b>	2Q
4D	5 17	3Q
5D	6 16	4Q
3D 4D 5D 6D 7D		5Q
7D	8 14	6Q
	9 10 11 12 13	
	300 200 200 200 200 200 200	

state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

тд	PACKAG	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
			FART NUMBER	WARKING	
	PDIP – N	Tube	SN74HCT573N	SN74HCT573N	
–40°C to 85°C	SOIC - DW	Tube	SN74HCT573DW	HCT573	
	3010 - 010	Tape and reel	SN74HCT573DWR	пст575	
	SOP – NS	Tape and reel	SN74HCT573NSR	HCT573	
	SSOP – DB	Tape and reel	SN74HCT573DBR	HT573	
	TSSOP – PW	Tube	SN74HCT573PW	HT573	
	1330F - FW	Tape and reel	SN74HCT573PWR		
	CDIP – J	Tube	SNJ54HCT573J	SNJ54HCT573J	
–55°C to 125°C	CFP – W	Tube	SNJ54HCT573W	SNJ54HCT573W	
	LCCC – FK	Tube	SNJ54HCT573FK	SNJ54HCT573FK	

#### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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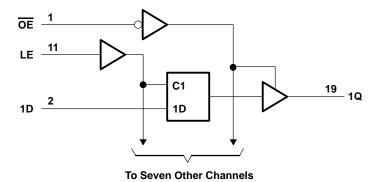
#### SN54HCT573, SN74HCT573 **OCTAL TRANSPARENT D-TYPE LATCHES** WITH 3-STATE OUTPUTS SCLS176E - MARCH 1984 - REVISED JULY 2003

#### description/ordering information (continued)

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

	FUNCTION TABLE (each latch)											
	INPUTS	OUTPUT										
OE	LE	Q										
L	Н	Н	Н									
L	н	L	L									
L	L	Х	Q <sub>0</sub>									
н	Х	Х	z									

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub>	
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ ) (see N	Note 1) ±20 mA
Output clamp current, $I_{OK}$ (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> ) (	see Note 1) ±20 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	±35 mA
Continuous current through V <sub>CC</sub> or GND	±70 mA
Package thermal impedance, $\theta_{JA}$ (see Note 2): D	B package
D	N package 58°C/W
Ν	package 69°C/W
N	S package 60°C/W
P	<i>N</i> package
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



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#### recommended operating conditions (see Note 3)

			SN	54HCT5	i73	SN	74HCT5	73	UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2			2			V
VIL	Low-level input voltage	$V_{CC} = 4.5 V \text{ to } 5.5 V$		44	0.8			0.8	V
VI	Input voltage		0	5	VCC	0		VCC	V
Vo	Output voltage		0 🗸	20	VCC	0		VCC	V
$\Delta t/\Delta v$	Input transition rise/fall time		30	)	500			500	ns
Т <sub>А</sub>	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	vcc	Т	A = 25°C	;	SN54H0	CT573	SN74HCT573		UNIT	
PARAMETER	TEST CO		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
Vou	VI = VIH or VIL	I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
VOH	AI = AIH OLAIT	I <sub>OH</sub> =6 mA	4.5 V	3.98	4.3		3.7	h	3.84		v
Vo	VI = VIH or VIL	I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL		I <sub>OL</sub> = 6 mA	4.5 V		0.17	0.26		0.4		0.33	v
l	$V_{I} = V_{CC} \text{ or } 0$		5.5 V		±0.1	±100	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	±1000		±1000	nA
I <sub>OZ</sub>	AO = ACC  or  0		5.5 V		±0.01	±0.5	202	±10		±5	μA
ICC	$V_{I} = V_{CC} \text{ or } 0,$	l <sub>O</sub> = 0	5.5 V			8	201	160		80	μA
∆lcc <sup>†</sup>	One input at 0.5 \ Other inputs at 0	5.5 V		1.4	2.4	Q	3		2.9	mA	
Ci			4.5 V to 5.5 V		3	10		10		10	pF

<sup>†</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.

# timing requirements over recommended operating free-air temperature range (unless otherwise noted)

		Vee		T <sub>A</sub> = 25°C		SN54HCT573		SN74HCT573	
		Vcc	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
•	Pulse duration, LE high		20		30	VIE	25		ns
tw			17		27	RE	23		115
			10		15	' /	13		
t <sub>su</sub>	Setup time, data before LE $\downarrow$	5.5 V	9		14		12		ns
+.	Hold time, data after LE $\downarrow$		5		05		5		ns
<sup>t</sup> h			5		<b>Q</b> 5		5		



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#### switching characteristics over recommended operating free-air temperature range, C<sub>L</sub> = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Vaa	Тд	_ = 25°C	;	SN54HCT573	SN74HCT573	UNIT	
FARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN MAX	MIN MAX	UNIT	
	D	Q	4.5 V		25	35	53	44		
<sup>t</sup> pd	D	ý	5.5 V		21	32	48	40	ns	
	LE	Any Q	4.5 V		28	35	53	44	115	
	LL	Ally Q	5.5 V		25	32	48	40		
•	OE	Any Q	4.5 V		26	35	53	44	20	
t <sub>en</sub>	ÛE	Ally Q	5.5 V		23	32	2 <sub>2</sub> 2 2 2	40	ns	
<b>t</b>	OE	Any Q	4.5 V		23	35	53	44	200	
<sup>t</sup> dis	ÛE	Ally Q	5.5 V		22	32	48	40	ns	
+.		Any Q	4.5 V		9	12	18	15	ns	
tt			5.5 V		9	11	16	14	115	

# switching characteristics over recommended operating free-air temperature range, $C_L = 150 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Vee	Т	<b>₄ = 25°C</b>	;	SN54HCT573	SN74HCT573	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	Vcc	MIN	TYP	MAX	MIN MAX	MIN MAX	UNIT	
	D	Q	4.5 V		32	52	79	65		
<b>.</b>	U	Ŷ	5.5 V		27	47	71	59	-	
<sup>t</sup> pd	LE	Any Q	4.5 V		38	52	79	65	ns	
	LL	Any Q	5.5 V		36	47	<b>Q</b> 71	59		
+	OE	Any Q	4.5 V		33	52	<b>O</b> 79	65	ns	
<sup>t</sup> en	ÛE	Any Q	5.5 V		28	47	Q 71	59	115	
+.			4.5 V		18	42	63	53	20	
tt		Any Q	5.5 V		16	38	57	48	ns	

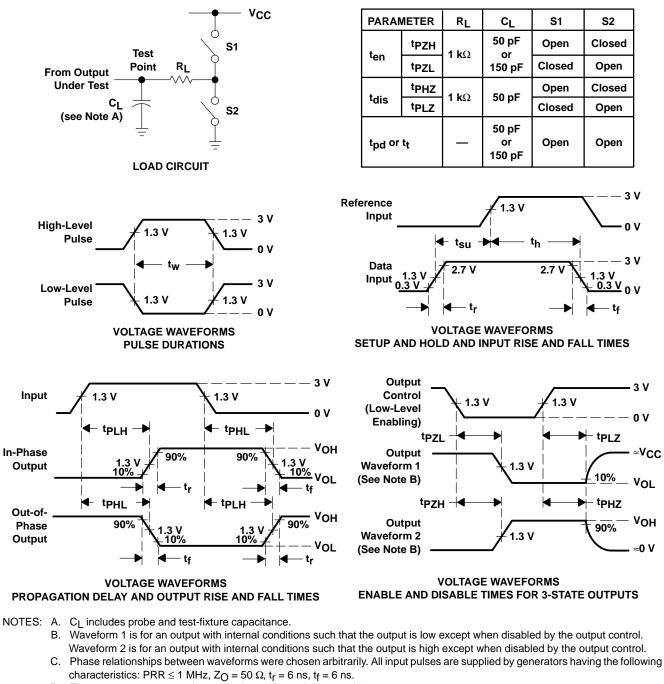
### operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance per latch	No load	50	pF



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#### PARAMETER MEASUREMENT INFORMATION



- D. The outputs are measured one at a time with one input transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. tp<sub>7</sub> and tp<sub>7</sub> are the same as  $t_{en}$ .
- G. tPLH and tPHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms





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### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74HCT573DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT573	Samples
SN74HCT573DBRG4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT573	Samples
SN74HCT573DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT573	Samples
SN74HCT573DWG4	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT573	Samples
SN74HCT573DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT573	Samples
SN74HCT573DWRE4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT573	Samples
SN74HCT573DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT573	Samples
SN74HCT573N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT573N	Samples
SN74HCT573NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT573	Samples
SN74HCT573PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT573	Samples
SN74HCT573PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT573	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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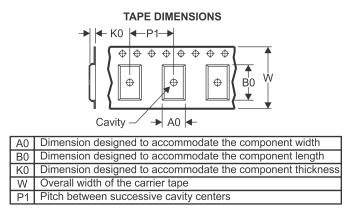
### PACKAGE MATERIALS INFORMATION

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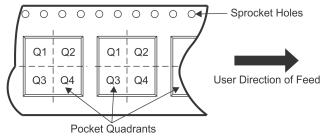
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#### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT573DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74HCT573DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HCT573NSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HCT573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

TEXAS INSTRUMENTS

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### PACKAGE MATERIALS INFORMATION

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT573DBR	SSOP	DB	20	2000	853.0	449.0	35.0
SN74HCT573DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74HCT573NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74HCT573PWR	TSSOP	PW	20	2000	853.0	449.0	35.0

### **DB0020A**



### **PACKAGE OUTLINE**

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



### DB0020A

### **EXAMPLE BOARD LAYOUT**

### SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### DB0020A

### **EXAMPLE STENCIL DESIGN**

### SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



#### MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  $\beta$ . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



### LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



### N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



### **DW0020A**



### **PACKAGE OUTLINE**

### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



### DW0020A

### **EXAMPLE BOARD LAYOUT**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### DW0020A

### **EXAMPLE STENCIL DESIGN**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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